

CM75BU-12H

HIGH POWER SWITCHING USE
INSULATED TYPE

CM75BU-12H



- Ic 75A
- VCES 600V
- Insulated Type
- 4-elements in a pack
- UL Recognized

Yellow Card No. E80276

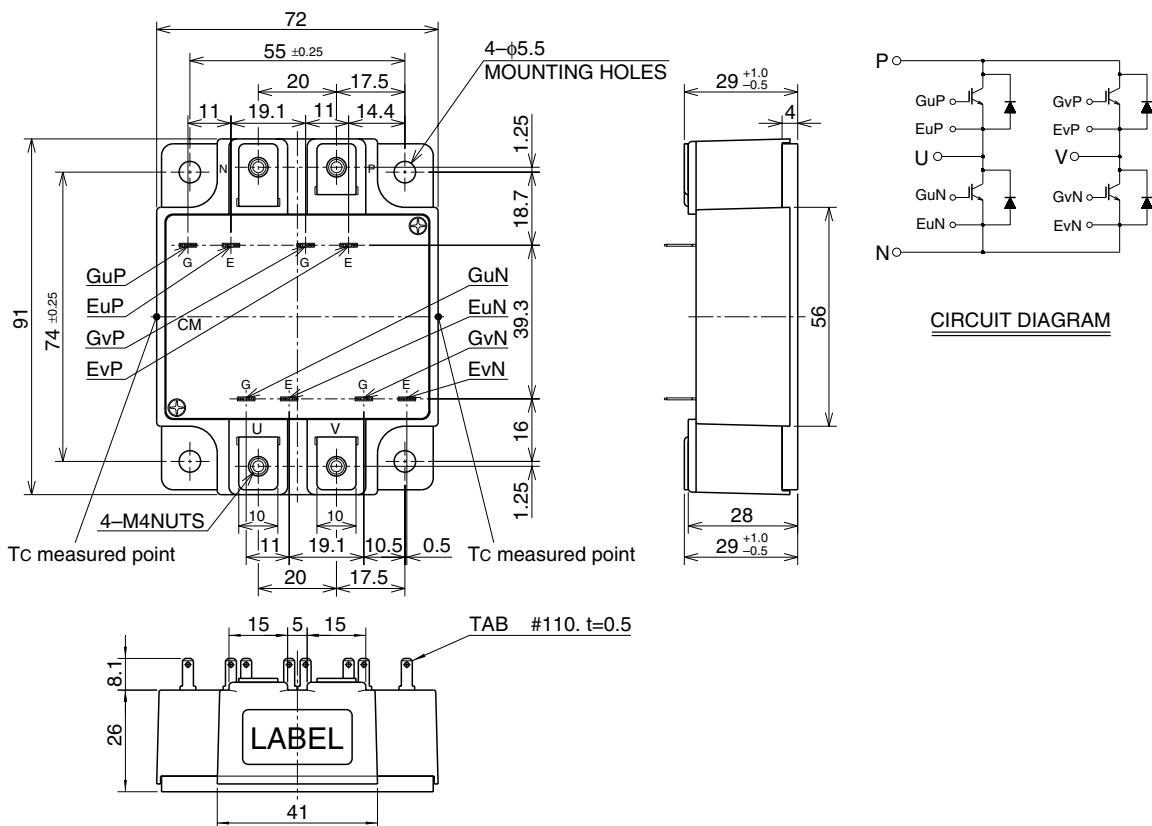
File No. E80271

APPLICATION

UPS, Welders

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



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MAXIMUM RATINGS (T_j = 25°C, unless otherwise specified)

| Symbol | Item | Conditions | Ratings | Unit |
|--------------------------|-------------------------------|---|------------|------------------|
| V _{CE} S | Collector-emitter voltage | V _{GE} = 0V | 600 | V |
| V _{GE} S | Gate-emitter voltage | V _{CE} = 0V | ±20 | V |
| I _C | Collector current | T _C = 25°C | 75 | A |
| I _{CM} | | Pulse (Note 1) | 150 | A |
| I _E (Note 2) | Emitter current | T _C = 25°C | 75 | A |
| I _{EM} (Note 2) | | Pulse (Note 1) | 150 | A |
| P _C (Note 3) | Maximum collector dissipation | T _C = 25°C | 310 | W |
| T _j | Junction temperature | — | -40 ~ +150 | °C |
| T _{stg} | Storage temperature | — | -40 ~ +125 | °C |
| V _{iso} | Isolation voltage | Charged part to base plate, f = 60Hz, AC 1 minute | 2500 | V _{rms} |
| — | Mounting torque | Main terminals M4 screw | 1.3 ~ 1.7 | N·m |
| | | Mounting M5 screw | 2.5 ~ 3.5 | N·m |
| — | Weight | Typical value | 390 | g |

ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise specified)

| Symbol | Item | Test Conditions | Limits | | | Unit | |
|--------------------------|--------------------------------------|--|------------------------|------|-----|------|---|
| | | | Min | Typ | Max | | |
| I _{CES} | Collector cutoff current | V _{CE} = V _{CE} S, V _{GE} = 0V | — | — | 1 | mA | |
| V _{GE(th)} | Gate-emitter threshold voltage | I _C = 7.5mA, V _{CE} = 10V | 4.5 | 6 | 7.5 | V | |
| I _{GES} | Gate-leakage current | ±V _{GE} = V _{GES} , V _{CE} = 0V | — | — | 0.5 | μA | |
| V _{CE(sat)} | Collector-emitter saturation voltage | I _C = 75A, V _{GE} = 15V (Note 4) | T _j = 25°C | — | 2.4 | 3.0 | V |
| | | | T _j = 125°C | — | 2.6 | — | |
| C _{ies} | Input capacitance | V _{CE} = 10V | — | — | 6.6 | nF | |
| C _{oes} | Output capacitance | V _{GE} = 0V | — | — | 3.6 | nF | |
| C _{res} | Reverse transfer capacitance | — | — | — | 1 | nF | |
| Q _G | Total gate charge | V _{CC} = 300V, I _C = 75A, V _{GE} = 15V | — | 150 | — | nC | |
| t _{d(on)} | Turn-on delay time | V _{CC} = 300V, I _C = 75A | — | — | 100 | ns | |
| t _r | Turn-on rise time | V _{GE} = ±15V | — | — | 250 | ns | |
| t _{d(off)} | Turn-off delay time | R _G = 8.3Ω | — | — | 200 | ns | |
| t _f | Turn-off fall time | Resistive load | — | — | 300 | ns | |
| V _{EC} (Note 2) | Emitter-collector voltage | I _E = 75A, V _{GE} = 0V | — | — | 2.6 | V | |
| t _{rr} (Note 2) | Reverse recovery time | I _E = 75A, | — | — | 160 | ns | |
| Q _{rr} (Note 2) | Reverse recovery charge | die / dt = -150A / μs | — | 0.18 | — | μC | |
| R _{th(j-c)Q} | Thermal resistance (Note 5) | Junction to case, IGBT part (Per 1/4 module) | — | — | 0.4 | K/W | |
| R _{th(j-c)R} | | Junction to case, FWDi part (Per 1/4 module) | — | — | 0.9 | K/W | |
| R _{th(c-f)} | Contact thermal resistance | Case to heat sink, conductive grease applied (Per 1/4 module) (Note 6) | — | 0.1 | — | K/W | |

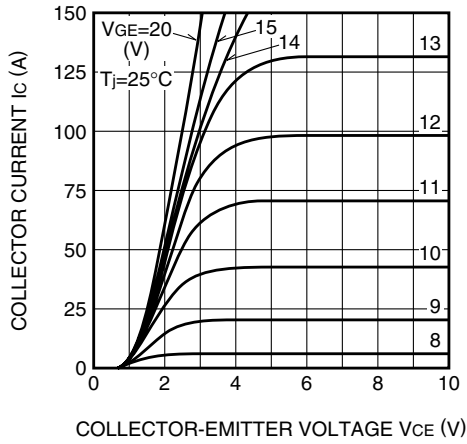
- Note 1. Pulse width and repetition rate should be such that the device junction temperature (T_j) does not exceed T_{jmax} rating.
 2. I_E, V_{EC}, t_{rr}, Q_{rr} & die/dt represent characteristics of the anti-parallel, emitter-collector free-wheel diode.
 3. Junction temperature (T_j) should not increase beyond 150°C.
 4. Pulse width and repetition rate should be such as to cause negligible temperature rise.
 5. Case temperature (T_C) measured point is shown in page OUTLINE DRAWING.
 6. Typical value is measured by using thermally conductive grease of λ = 0.9[W/(m · K)].

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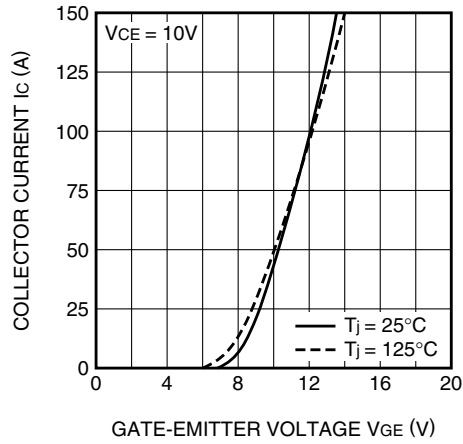
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PERFORMANCE CURVES

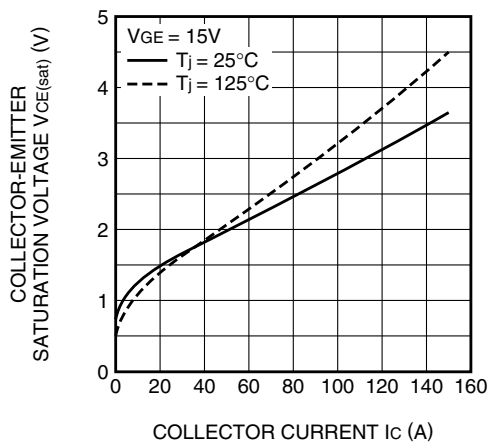
OUTPUT CHARACTERISTICS (TYPICAL)



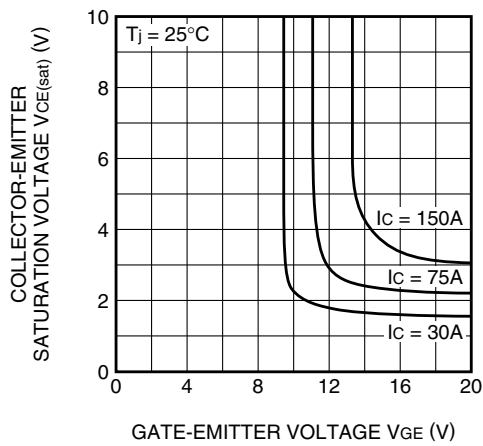
TRANSFER CHARACTERISTICS (TYPICAL)



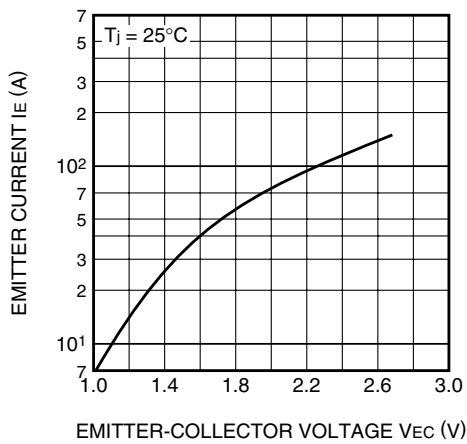
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



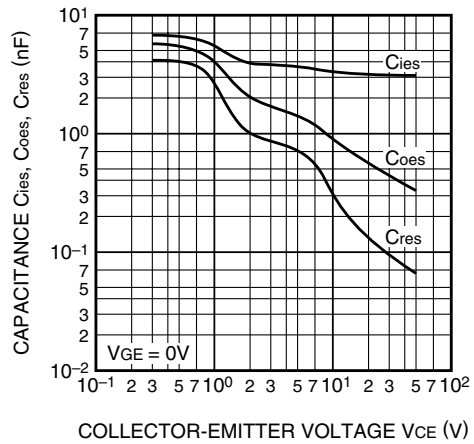
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)



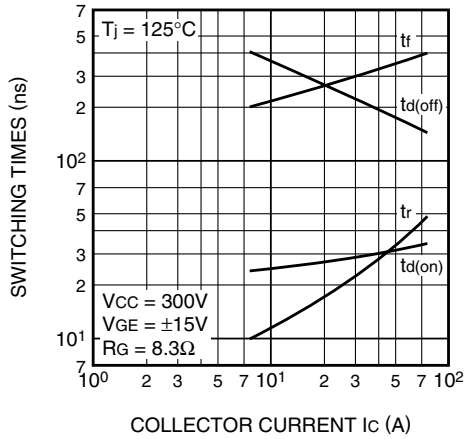
CAPACITANCE CHARACTERISTICS (TYPICAL)



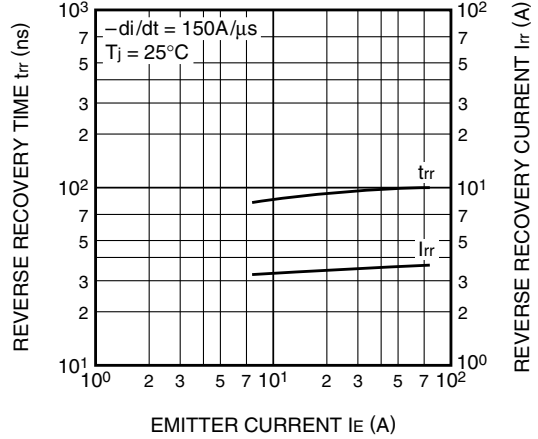
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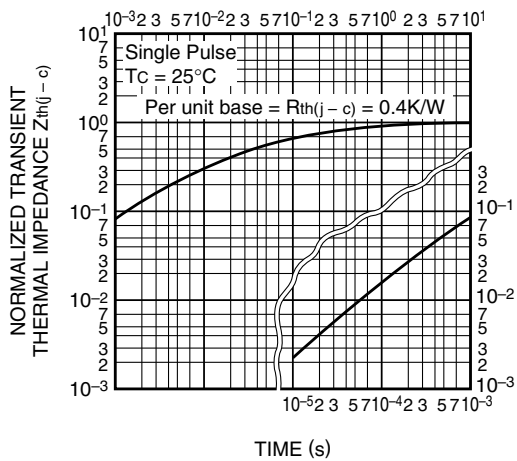
**HALF-BRIDGE
SWITCHING TIME CHARACTERISTICS
(TYPICAL)**



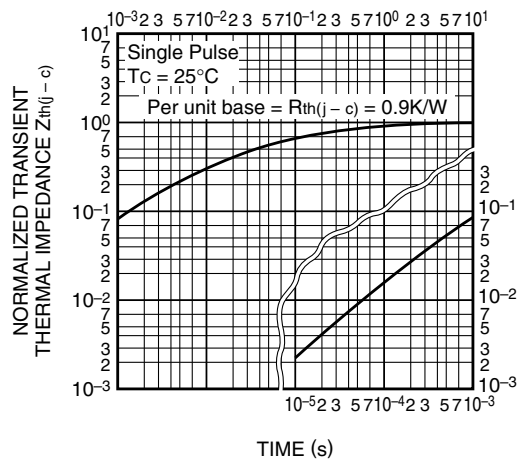
**REVERSE RECOVERY CHARACTERISTICS
OF FREE-WHEEL DIODE
(TYPICAL)**



**TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(IGBT part)**



**TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(FWDi part)**



**GATE CHARGE CHARACTERISTICS
(TYPICAL)**

